

Semiconductors nanostructures for bio-interface and life sciences**Adel Najar^{1,*}**¹NTT Basic Research Laboratories, NTT Corporation, 3-1, Morinosato-Wakamiya, Atsugi, Kanagawa 243-0198, Japan, e-mail: Adel.Najar@lab.ntt.co.jp**1. EDITORIAL**

Controlling the interaction between nanostructures and bio-systems is ongoing topic in the scientific community. In particular, inorganic semiconductor nanostructures (porous structures, nanowires, and nanoparticles) are interesting platform for ultrasensitive, direct detection of biological and chemical species based on optical and electrical responses. The contribution of Dutt *et al.* presents the synthesis of Polyaniline Nanostructure (PANI-NS) using swollen liquid crystal (SLC) as soft templates that show high sensitivity, low detection limits and better linear range of detection for the electrochemical detection of H_2O_2 as well as amperometric biosensing of glucose. The nanostructured PANI was not only highly sensitive for glucose sensing, but also showed very good selectivity for glucose against common biological interfering agents. Although the concept has been presented within the context of H_2O_2 sensing and glucose sensing, it could be readily extended to other biosensing applications. Various metal complexes are nowadays used in anticancer therapy and conducted to a large interest from chemists, biologists and organometallurgists to develop drugs of future. The low cytotoxicity of ferrocene and its malleability have made it an interesting

anticancer agent. Goumri-Said from Georgia Institute of Technology reports a theoretical modeling and computational study of the optical properties and electronic structure of ferrocene-substituted dithio-o-carborane conjugate in order to understand its structure and control its properties for future biological purposes. It is found that the ferrocene is a semiconductor with large bandgap, which may lead us to consider large possibilities to tailor its optical spectrum for special role depending on the environment. In this special issue, includes a mini-review paper by Jouiad *et al.* reports the structural properties of porous silicon nanowires (PSiNWs) fabricated using silver (Ag) ions assisted electroless etching method. The sensitivity of PSiNWs electrical properties to gaseous NO_x at room temperature was demonstrated. Also, the results showed that the surface-enhanced Raman spectroscopies (SERS)-active substrates prepared by this method are excellent candidates for MG molecules sensing with high sensitivity, good reproducibility and excellent stability. The excellent sensing performance coupled with scalable synthesis of porous SiNWs could open up opportunities in scalable production of sensor chips working at room temperature.